

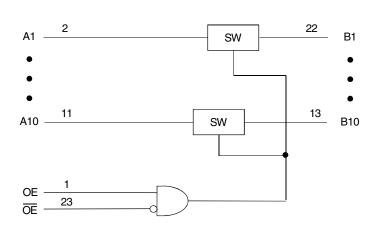
LOW-VOLTAGE 10-BIT BUS SWITCH WITH ACTIVE HIGH AND LOW ENABLES

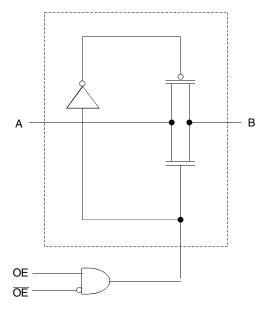
 FEATURES: 5Ω A/B bi-directional switch Isolation Under Power-Off Conditions Over-voltage tolerant Latch-up performance exceeds 100mA Vcc = 2.3V - 3.6V, normal range ESD >2000V per MIL-STD-883, Method 3015; >200V using machine model (C = 200pF, R = 0) Available in SSOP, QSOP, and TSSOP packages 	DESCRIPTION: The CBTLV3862 provides ten bits of high-speed bus switching with low on-state resistance of the switch allowing connections to be made with minimal propagation delay. The device is organized as one 10-bit bus switch. The switches are controlled by independent active-low enable (OE) and active-high enable (OE) controls. To ensure the high-impedance state during power up or power down, OE should be tied to Vcc through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver, and OE should be tied to GND.
APPLICATIONS: • 3.3V High Speed Bus Switching and Bus Isolation	

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FUNCTIONAL BLOCK DIAGRAM

SIMPLIFIED SCHEMATIC, EACH SWITCH



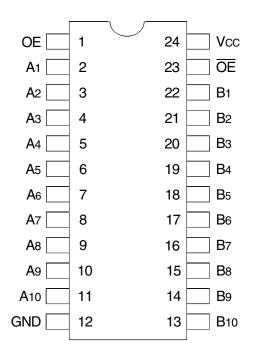


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IDT74CBTLV3862 LOW-VOLTAGE 10-BIT BUS SWITCH WITH ACTIVE HIGH AND LOW ENABLES

PINCONFIGURATION



SSOP/ QSOP/ TSSOP TOP VIEW

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max.	Unit
Vcc	Supply Voltage Range	-0.5 to 4.6	V
Vi	Input Voltage Range	-0.5 to 4.6	V
	Continuous Channel Current	128	mA
Ік	Input Clamp Current, VI/O < 0	-50	mA
Tstg	Storage Temperature Range	-65 to +150	°C

NOTE:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

FUNCTION TABLE⁽¹⁾

Inp	outs		
OE	ŌĒ	Function	
L	L	Disconnect	
L	Н	Disconnect	
Н	L	A Port = B Port	
Н	Н	Disconnect	

NOTE:

1. H = HIGH Voltage Level

L = LOW Voltage Level

OPERATING CHARACTERISTICS⁽¹⁾

Symbol	Parameter	Test Conditions	Min.	Max.	Unit
Vcc	Supply Voltage		2.3	3.6	V
Vih	High-Level Control Input Voltage	Vcc = 2.3V to 2.7V	1.7	—	V
		Vcc = 2.7V to 3.6V	2		
Vil	Low-Level Control Input Voltage	Vcc = 2.3V to 2.7V	—	0.7	V
		Vcc = 2.7V to 3.6V	—	0.8	
TA	Operating Free-Air Temperature		-40	+85	°C

NOTE:

1. All unused control inputs of the device must be held at Vcc or GND to ensure proper device operation.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified: Operating Condition: TA = -40° C to $+85^{\circ}$ C

Symbol	Parameter	Test Conditions		Min.	Typ. ⁽¹⁾	Max.	Unit
Vik	Control Inputs, Data I/O	Vcc = 3V, II = -18mA		_	—	-1.2	V
lı	Control Inputs, Data I/O	Vcc = 3.6V, VI = Vcc or GNE)	_	—	±1	μA
loz	Data I/O	Vcc = 3.6V, Vo = 0V or 3.6V	switch disabled	_	—	5	μA
IOFF		Vcc = 0V, VI or Vo = 0V or 3	.6V	_	—	50	μA
lcc		VCC = 3.6V, IO = 0, VI = VCC	or GND	_	—	10	μA
$\Delta ICC^{(2)}$	Control Inputs	Vcc = 3.6V, one input at 3V, other inputs at Vcc or GND		_	—	300	μA
Сі	Control Inputs	VI = 3V or 0		_	4	_	pF
CIO(OFF)		Vo = 3V or 0 (switch off)		_	6	_	pF
	Vcc = 2.3V	VI = 0	Io = 64mA	_	5	8	
	Typ. at Vcc = 2.5V		lo = 24mA	—	5	8	
Ron ⁽³⁾		VI = 1.7V	lo = 15mA	_	27	40	Ω
		VI = 0	Io = 64mA	_	5	7	
	Vcc = 3V		lo = 24mA	_	5	7	
		VI = 2.4V	lo = 15mA	_	10	15]

NOTES:

1. Typical Values are at Vcc = 3.3V, +25°C ambient.

2. The increase in supply current is attributable to each input that is at the specified voltage level rather than Vcc or GND.

3. This is measured by the voltage drop between the A and B terminals at the indicated current through the switch.

SWITCHING CHARACTERISTICS

	Vcc = 2.5V ± 0.2V		$Vcc = 3.3V \pm 0.3V$			
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit
tpd ⁽¹⁾	Propagation Delay	-	0.15	—	0.25	ns
	A to B or B to A					
ten	Output Enable Time	1	4.5	1	4.2	ns
	OE to A or B					
tdis	Output Disable Time	1	5	1	5	ns
	OE to A or B					
ten	Output Enable Time	1	4.5	1	4.2	ns
	OE to A or B					
tdis	Output Disable Time	1	5	1	6	ns
	OE to A or B					

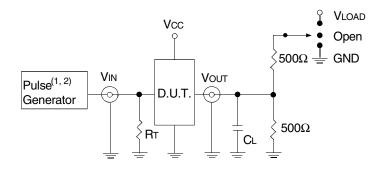
NOTE:

1. The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance when driven by an ideal voltage source (zero output impededance).

TEST CIRCUITS AND WAVEFORMS

TESTCONDITIONS

Symbol	Vcc ⁽¹⁾ =3.3V±0.3V	Vcc ⁽²⁾ =2.5V±0.2V	Unit
VLOAD	6	2 x Vcc	V
Vih	3	Vcc	V
Vτ	1.5	Vcc/2	V
Vlz	300	150	mV
Vhz	300	150	mV
Cl	50	30	pF



Test Circuits for All Outputs

DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.

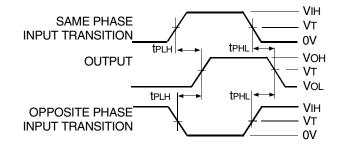
NOTES:

1. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2.5ns; tR \leq 2.5ns.

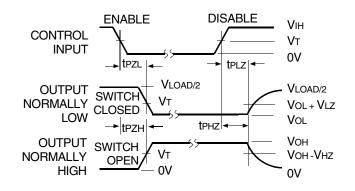
2. Pulse Generator for All Pulses: Rate \leq 10MHz; tr \leq 2ns; tr \leq 2ns.

SWITCH POSITION

Test	Switch
telz/tezl	VLOAD
tphz/tpzh	GND
tpd	Open



Propagation Delay

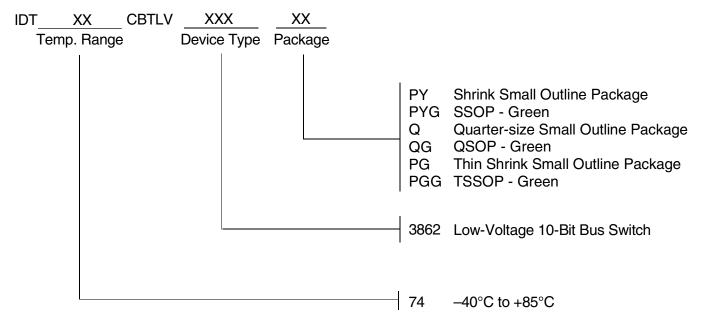


NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

Enable and Disable Times

ORDERING INFORMATION





CORPORATE HEADQUARTERS 6024 Silver Creek Valley Road San Jose, CA 95138 for SALES: 800-345-7015 or 408-284-8200 fax: 408-284-2775 www.idt.com for Tech Support: logichelp@idt.com